



SiC-based UV photodiode

Model STV-ABC-M

General Features:

- Single voltage supply operation
- Direct voltage output
- TO-39 metal housing with sapphire window
- High sensitivity and good linearity
- Integrated solution in a single package

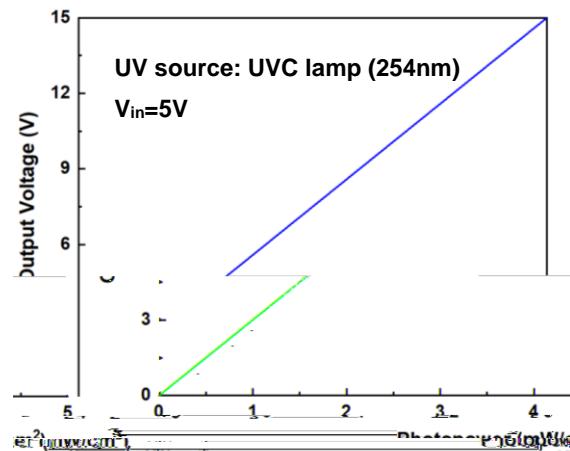


Applications: UV-C monitoring, UV radiation dose measurement, flame detection

Specifications:

Parameters	Symbol	Value	Unit
Maximum ratings			
Operation temperature range	T _{opt}	-25-85	°C
Storage temperature range	T _{sto}	-40-85	°C
Soldering temperature (3 s)	T _{sol}	260	°C
Supply voltage	V _{in}	5	V
General characteristics (25 °C)			
Chip size	A	0.24	mm ²
Temperature coefficient	T _c	-0.02	%/°C
Spectral response characteristics (25 °C)			
Responsivity (at 254nm)	R	0.1	mV/nW
Output Voltage	V _{out}	0-5	V
Offset Voltage	V _{off}	0.02	V
Detection Power Range	P	0-15	mW/cm ²
Rising Time	T _r	2	μS

Output Voltage vs UV power



Package dimension

